

Pattern Manipulation via On-chip Phase Modulation between OAM Beams

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An integrated approach to thermal modulation of relative phase between two optical vortices with opposite chirality has been demonstrated on a silicon-on-insulator (SOI) substrate. The device consists of a silicon-integrated optical vortex emitter and a phase controlled 3dB coupler. The relative phase between two optical vortices can be actively modulated on chip by applying a voltage on the integrated heater. The phase shift is shown to be linearly proportional to applied electrical power, and the rotation angle of the interference pattern are observed to be inversely proportional to topological charge. This scheme can be used in lab-on-chip, communications and sensing applications. It can be intentionally implemented with other modulation elements to achieve more complicated applications.

The concept of angular momentum was first discussed by Poynting in 1909¹ and it was realized that circular polarized light has angular momentum, which is spin angular momentum (SAM) of $\pm \hbar$ per photon. Until 1992, Allen et al. recognized that light beams with an azimuthal phase dependence of $\exp(il\phi)$ carries orbital angular momentum (OAM) independent of the polarization state². l is the topological charge that can take any integer value and ϕ is the azimuthal coordinate. The significance of Allen's study was that OAM is a natural character of all helical phased beams, and may lead to a wide range of applications. Various methods have been established to produce light with OAM, such as spiral phase plates (SSP)³, diffractive optical elements^{4,5}, mode converters^{6,7} sub-wavelength gratings⁸, and nano-antennas⁹.

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In many applications^{10,11}, the capabilities to generate two collinear OAM beams and to modulate the relative phase between OAM beams are highly desirable in optical manipulations and transmission systems^{12,13}. For example, D'Ambrosio *et al.* overlapped two OAM beams with the topological charge of $\pm l$ to generate so-called 'photonic gears', which greatly enhanced the angular measurement precision¹⁴. In parallel with this work, M. P. J. Lavery *et al.* demonstrated a way to detect the angular speed of a spinning object using two OAM beams with opposite values of l ¹⁵. However, the superposition of the OAM states are generated by bulky and expensive components, like SLM, which limits the prospect of its wide use in future photonic technology.

In 2012, X. Cai *et al.* developed an optical OAM beam emitter based on $36\ \mu\text{m}$ -sized micro-ring resonators¹⁶. The principle of operation of this integrated OAM device is to couple the rotating whispering gallery mode (WGM) of micro ring resonator to a vertically emitted propagating OAM mode. By matching the wavelength of the light with the micro-ring resonator, and by detuning from the Bragg grating resonance, this devices is capable of emitting a propagating field of any desired OAM state. Shortly after, the design was further refined by integrating resistive heating elements on the waveguide, such that the fast switching of OAM modes could be achieved¹⁷. In this work, we demonstrate an integrated approach to simultaneous generation of a pair of OAM modes with opposite topological charge by integrating the micro-ring OAM device with phase controlled 3dB couplers. The relative phase between two OAM beams can be actively modulated on chip by only applying a voltage on the heater integrated with the waveguide.

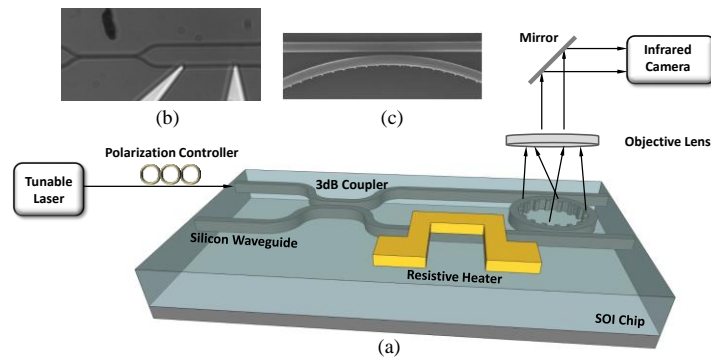


FIG. 1. (a) Schematic of the phase modulated OAM emitter, (b) the optical image of the 3dB coupler and the thermal heater, (c) the SEM images of the ring and access waveguide.

The experimental setup of the waveguide-based ring emitter device is illustrated in Fig. 1(a). The device was designed and tested in University of Bristol and fabricated in University of Glasgow. It was fabricated on a silicon-on-insulator (SOI) substrate with silicon waveguides (500 nm wide, 220 nm thick) and a $2\ \mu\text{m}$ buried oxide layer. The ring was defined with a radius of $36\ \mu\text{m}$ with 360 grating elements. The period of the grating is 600 nm, about one wavelength in the ring resonator to form a second-order Bragg grating for the wavelength of 1530 nm. The width of the grating elements is 60 nm; that is about 1/10 of the grating period. The gap between the ring and the straight waveguide is

200 nm. The structures were defined using direct-write electron-beam lithography in a Hydrogen Silsequioxane (HSQ) negative photoresist layer, followed by a Reactive Ion Etching (RIE) process to transfer the Photonic Integrated Circuit (PIC) pattern into the silicon layer. Subsequently, a layer of silicon dioxide 900 nm thick was coated onto the wafer as the buffer layer between the silicon layer and metal contact layers. The thermo phase shifter was produced with 50 nm of nickel chromium. A 200 nm thick Au layer was then patterned as the electrical transmission lines to the heater element. The output waveguide is tapered at both ends of the access in order to allow more efficient coupling from the input fibre and to reduce the Fabry-Perot resonance effects caused by optical reflection from the facets.

A fibre-optic polarization controller is used to adjust light into the quasi-TE mode. By splitting the input power with a 3 dB coupler, a light from the high precision tunable laser is injected into both clockwise (CW) and counter-clockwise (CCW) directions of the micro-ring, therefore two complementary OAM beams with opposite topological charges are emitted. The resistive thermal heater, located on one of the input waveguides, modulate the relative phase of the light in two waveguides and hence the relative phase between the two OAM beams. Fig. 1(b) shows the optical image of the waveguide based 3dB coupler and the resistive heater. A scanning electron microscope (SEM) image of a part of the micro-ring with inside gratings has shown in Fig. 1(c).

The output of the device is a superposition of two OAM beams, and the transverse field components of a emitted OAM beam can be expressed as¹⁸¹⁹:

$$E_{\rho,\ell} = (-j)^\ell \frac{A v^2 \Phi(\rho, \zeta)}{\sqrt{\rho^2 + \zeta^2}} \exp(j\ell\varphi) (J_{\ell+1} + J_{\ell-1}) \quad (1)$$

$$E_{\varphi,\ell} = (-j)^{\ell+1} \frac{A v^2 \Phi(\rho, \zeta)}{\sqrt{\rho^2 + \zeta^2}} \exp(j\ell\varphi) (J_{\ell+1} - J_{\ell-1}) \quad (2)$$

In the above equations, (ρ, φ, ζ) is the dimensionless cylindrical coordinate. The constant $A = P_A q / 8\pi\epsilon_0 R^3$ where P_A is the uniform dipole moment as described in the dipole-emission-based theoretical model for the integrated optical vortex emitter. The normalized propagation constant $v = 2\pi R / \lambda$ (λ is the vacuum wavelength) and ℓ is the topological charge of the emitted beam. The propagation phase factor $\Phi(\rho, \zeta) = \exp[jv(2\zeta^2 + \rho^2 + 1)/2\zeta]$, and $J_i \equiv J_i(v\rho/\zeta)$ denotes the i^{th} order Bessel function of the first kind. In the case of the superposition of two emitted beams, the field components from the interference between the two OAM beams with opposite topological charges and an initial phase difference of θ are:

$$E_\rho = E_{\rho,\ell} + \exp(j\theta)E_{\rho,-\ell} = (-j)^\ell 2j \frac{A\nu^2\Phi(\rho,\zeta)}{\sqrt{\rho^2 + \zeta^2}} \sin\left(\ell\varphi - \frac{\theta}{2}\right) \exp(j\frac{\theta}{2})(J_{\ell+1} + J_{\ell-1}) \quad (3)$$

$$E_\varphi = E_{\varphi,\ell} + \exp(j\theta)E_{\varphi,-\ell} = -(-j)^\ell 2j \frac{A\nu^2\Phi(\rho,\zeta)}{\sqrt{\rho^2 + \zeta^2}} \cos\left(\ell\varphi - \frac{\theta}{2}\right) \exp(j\frac{\theta}{2})(J_{\ell+1} - J_{\ell-1}) \quad (4)$$

The intensity distribution then becomes:

$$|E_r|^2 = |E_\rho|^2 + |E_\varphi|^2 = \frac{4A^2\nu^4}{\rho^2 + \zeta^2} [J_{\ell+1}^2 + J_{\ell-1}^2 - 2J_{\ell+1}J_{\ell-1} \cos(2\ell\varphi - \theta)] \quad (5)$$

The device has been characterized at room temperature. The emission spectrum for the device is measured by scanning the wavelength of the input laser as shown in Fig. 2(a). The mode splitting at 1545nm is caused by the cross coupling between the lights in two propagating directions in the ring. The strongest coupling exist at $l = 0$ because of the second order Bragg reflection so it could be used as the signature of the $l = 0$ mode¹⁶. At each resonance in the shorter or longer wavelength from $l = 0$, a pair of OAM beams with opposite l are emitted. These two OAM beams interfere with each other, forming a petal pattern with $2|l|$ lobes in the azimuthal direction, as shown in Fig. 2 (b), with un-biased resistive heater. It can be seen that the measured results agree well with the numerical simulations in Fig. 2 (c). The diffracted pattern for the emitted two OAM beams forms the fringe pattern with the number of $2|l|$ radial petals.

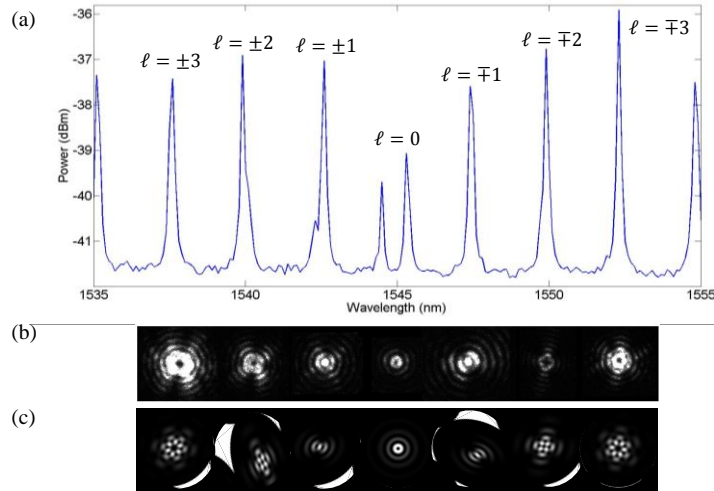


FIG. 2. (a) Vertical emission spectrum of the device measured by scanning the wavelength of the input laser (the \pm and \mp indicate short and long wavelength resonances emitting OAM modes with opposite signs), (b) measured intensity distributions of optical vortex pairs while the resistive heater is un-biased, (c) simulated interference patterns.

To change the relative phase between the $\pm l$ beams, a voltage between 0-5.2 V (corresponding to dissipated power of 0-20.8 mW) is applied to the thermal heater by wire bonding the on-chip transmission lines. The resistive heater had a series resistance of 1.5 k Ω . The value of term θ in Eq. (5) then changes with the applying voltage so that the phase shift is manifested in the rotation of the interference pattern between the two OAM beams. A thermal electric cooler (TEC) is used for controlling the device temperature, ensured that the thermal heater on the straight waveguide would not affect the radiated resonance of the micro-ring.

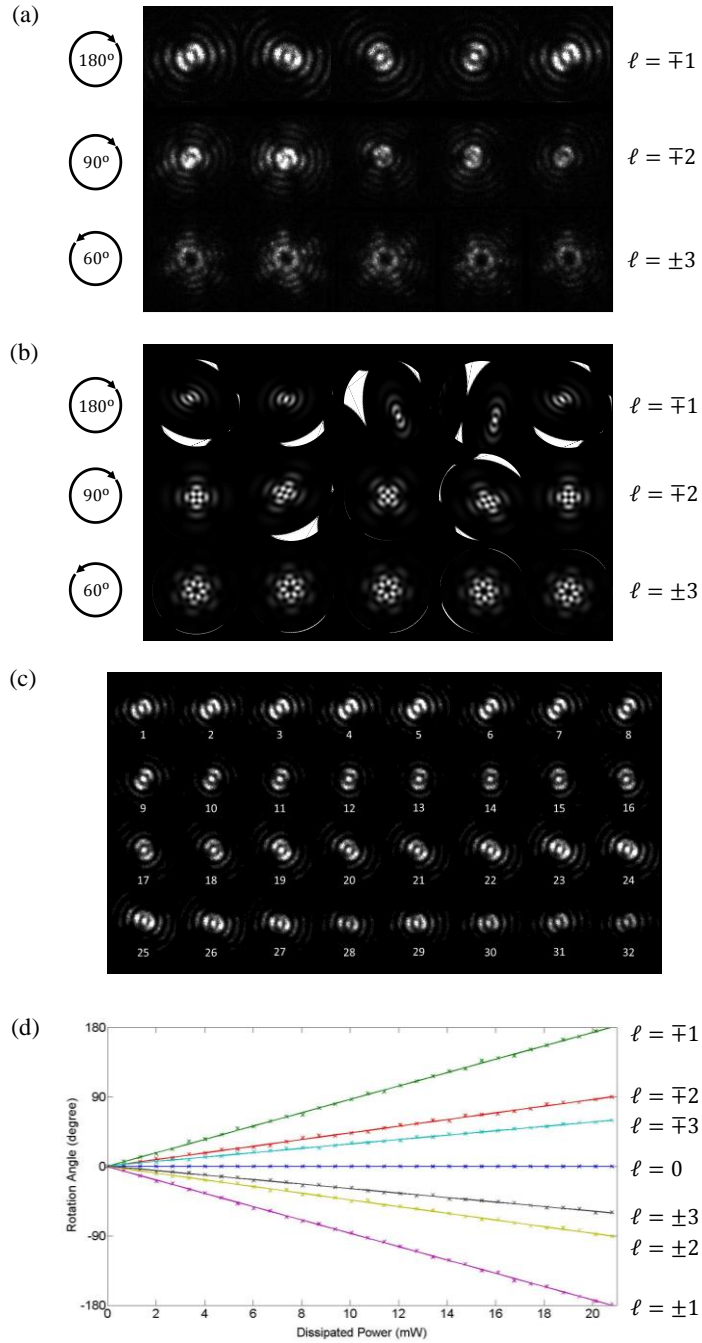


FIG. 3. (a) Measured intensity distributions of three selected OAM beams at different heater powers (0 mW, 5.37 mW, 10.74 mW, 16.1 mW and 20.8 mW), (b) corresponding simulated far field intensity distribution of OAM beams at different intermodal phase shift (0, $\pi/2$, π , $3\pi/2$)

and 2π), (c) Rotation of the interference pattern ($l = \pm 1$) with various phase shifts between two OAM beams, (d) Rotation angles of various topological charges with the increasing applied power on the resistive heater.

Fig. 3(a) displays the rotating trend under different voltages with the interference pattern of $l = \mp 1$, $l = \mp 2$ and $l = \pm 3$ modes at five applied voltages, which is in very good agreement with numerical simulations shown in Fig. 3(b). It can be seen that under the same applied voltage, the petal pattern formed by mode pairs of different $|l|$ rotate at different rates ($\pi/|l|$) and those with different signs (\pm or \mp) have different direction of rotation. In all of three OAM states, the rotating petal patterns stay same shape, indicating that the OAM states do not change. It should be note that the fuzzy patterns for $l = \mp 2$ and $l = \pm 3$ are captured by the IR camera that is not easy to get a clear interference pattern if it is complicated. The dynamic range of the IR camera is limited, which means parts of the pattern are easily saturated while the other parts cannot be revealed. Fig. 3(c) displays the rotating pattern of mode $l = \pm 1$ with 32 samples. With the increasing electrical power (0-20.8mW), the image gradually rotates 180° while the pattern shape does not change. In Fig. 2(b), Fig. 3(a) and Fig. 3(c), the interference patterns form a set of spots. This is because the wave-front of the two OAM beams have the same curvature, in which case their Gouy-phase shifts tend to be zero so the interference pattern looks like $2|l|$ intense spots of light²⁰.

Due to the cylindrically symmetric angular grating structure and the state of polarization of the source WGMs, the emitted lights from the micro-ring are cylindrical vector beams²¹. The radiated beam is the Jones vector that can be described as the superposition of two orthogonal scalar waves. It has been experimentally demonstrated by X. Cai that a radiated OAM beam with topological charge of l from the ring resonator can be decomposed into the superposition of two OAM beams with topological charges of $l + 1$ and $l - 1$, respectively¹⁶. Therefore, only in the petal patterns of $l = \mp 1$ and $l = \pm 1$, there is a bright spot at the center indicating the J_0 component.

A plot of rotation angle for different optical vortex pairs against dissipated power is shown in Fig. 3(d). The experimental results show that the rotation angles, and therefore the phase shifts, have linear relationships with the dissipated power, at different slopes depending on the value of l and the wavelength detuning. The $l = 0$ mode does not rotate. For others, the rotation is more pronounced in lower order mode beams. At the power of 20.8mW, $l = \mp 1$ and $l = \mp 2$ and $l = \mp 3$ modes rotate 180° , 90° and 60° clockwise, respectively. On the other hand, $l = \pm 1$, $l = \pm 2$ and $l = \pm 3$ modes rotate 180° , 90° and 60° counter-clockwise, respectively. It can be seen that the slopes of the rotation rate are proportional to $\pi/|l|$, which agrees with the cosinusoidally-varying intensity $\cos(2l\varphi - \theta)$ in Eq. (5).

On-chip thermal modulation of relative phase between pairs of OAM beams with opposite signs has been demonstrated using a silicon photonic PIC. The experiment results show that changing the relative phase between the two collinear OAM beams leads to the rotation of the interference pattern. The phase shift is linearly proportional to applied electrical power, and the rotating angles are shown to be inversely proportional to topological charge with the same power. This is the promising integrated approach to generating OAM beams with

superposition states and controlling the phase between two OAM modes on an integrated silicon device. The scheme can be applied to lab-on-chip, optical trapping^{22,23}, sensing^{15,24}, and phase encoding of OAM modes.

On conclusion, we demonstrate the proof of concept of OAM integrated functional circuit which composed of more than one devices, and the success of this circuits not only demonstrate OAM superposition states generation, but also pave the way for more complicated function OAM integrated circuits which requires large number of components integrated monolithically. In the future, this integrated silicon micro-ring structure can be intentionally implemented with other modulation elements to achieve more complicated applications. For example, a thermo-optical resistive heater can be connected with the ring cavity to actively switch emitted OAM mode of the superposition states¹⁷. Also, if a Mach-Zehnder interferometers can be integrated with the phase modulation structure. We can modulate not only the relative phase between two OAM modes, but also their amplitudes.

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